TOSHIBA Field Effect Transistor Silicon N Channel MOS Type (U-MOSIV)

## **TPC6011**

# Notebook PC Applications Portable Equipment Applications

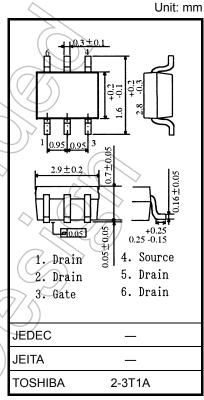
• Low drain-source ON-resistance:  $RDS(ON) = 16 \text{ m}\Omega \text{ (typ.)}$ 

 $(V_{GS} = 10V)$ 

- Low leakage current:  $IDSS = 10 \mu A (max) (VDS = 30 V)$
- Enhancement mode:  $V_{th} = 1.3$  to 2.5 V ( $V_{DS} = 10$  V,  $I_{D} = 1$  mA)

#### Absolute Maximum Ratings (Ta = 25°C)

-				- (1)
Characteristics	Symbol	Rating	Unit	
Drain-source voltage	$V_{DSS}$	30	$(\checkmark v)$	
Drain-gate voltage (R <sub>GS</sub> =	$V_{DGR}$	30	A	
Gate-source voltage	V <sub>GSS</sub>	±20	V	
Drain current	DC (Note 1)	ΙD	6	A
	Pulse (Note 1)	I <sub>DP</sub>	24	A
Drain power dissipation	ssipation (t = 5 s) (Note 2a)		2.2	⟨w
Drain power dissipation	(t = 5 s) (Note 2b)	PD	0.7	W
Single pulse avalanche ene	(E <sub>AS</sub>	2.3	mJ	
Avalanche current	JAR	3	A	
Channel temperature	√\ T <sub>ch</sub>	150	√°C	
Storage temperature range	√T <sub>stg</sub>	-55 to 150	°C	



Weight: 0.011 g (typ.)

Note: Using continuously under heavy loads (e.g. the application of high temperature/current/voltage and the significant change in temperature, etc.) may cause this product to decrease in the reliability significantly even if the operating conditions (i.e. operating temperature/current/voltage, etc.) are within the absolute maximum ratings. Please design the appropriate reliability upon reviewing the Toshiba Semiconductor Reliability Handbook ("Handling Precautions"/"Derating Concept and Methods") and individual reliability data (i.e. reliability test report and estimated failure rate, etc).

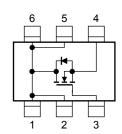
#### **Thermal Characteristics**

Characteristics	Symbol	Max	Unit
Thermal resistance, channel to ambient $(t=5\;\text{s}) \tag{Note 2a}$	R <sub>th (ch-a)</sub>	56.8	°C/W
Thermal resistance, channel to ambient $(t=5\;s) \eqno(Note\;2b)$	R <sub>th (ch-a)</sub>	178.5	°C/W

Note: (Note 1), (Note 2), (Note 3): See other pages.

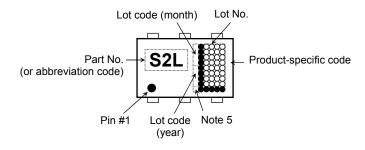
This transistor is an electrostatic-sensitive device. Please handle with caution.

#### **Circuit Configuration**



Start of commercial production 2009-07

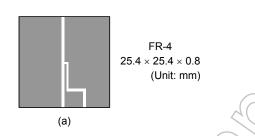
#### Marking (Note 4)

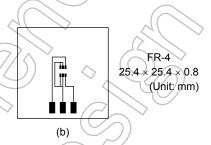


Note 1: Ensure that the channel temperature does not exceed 150°C.

Note 2: (a) Device mounted on a glass-epoxy board (a) (t = 5 s)

(b) Device mounted on a glass-epoxy board (b) (t = 5 s)





Note 3:  $V_{DD} = 24 \text{ V}$ ,  $T_{ch} = 25^{\circ}\text{C}$  (initial),  $L = 200 \,\mu\text{H}$ ,  $R_G = 25 \,\Omega$ ,  $I_{AR} = 3 \,\text{A}$ 

Note 4: • on lower left of the marking indicates Pin 1.

Note 5: A dot marking identifies the indication of product Labels.

Without a dot: [[Pb]]/INCLUDES > MCV

With a dot: [[G]]/RoHS COMPATIBLE or [[G]]/RoHS [[Pb]]

Please contact your TOSHIBA sales representative for details as to environmental matters such as the RoHS compatibility of Product. The RoHS is the Directive 2011/65/EU of the European Parliament and of the Council of 8 June 2011 on the restriction of the use of certain hazardous substances in electrical and electronic equipment.

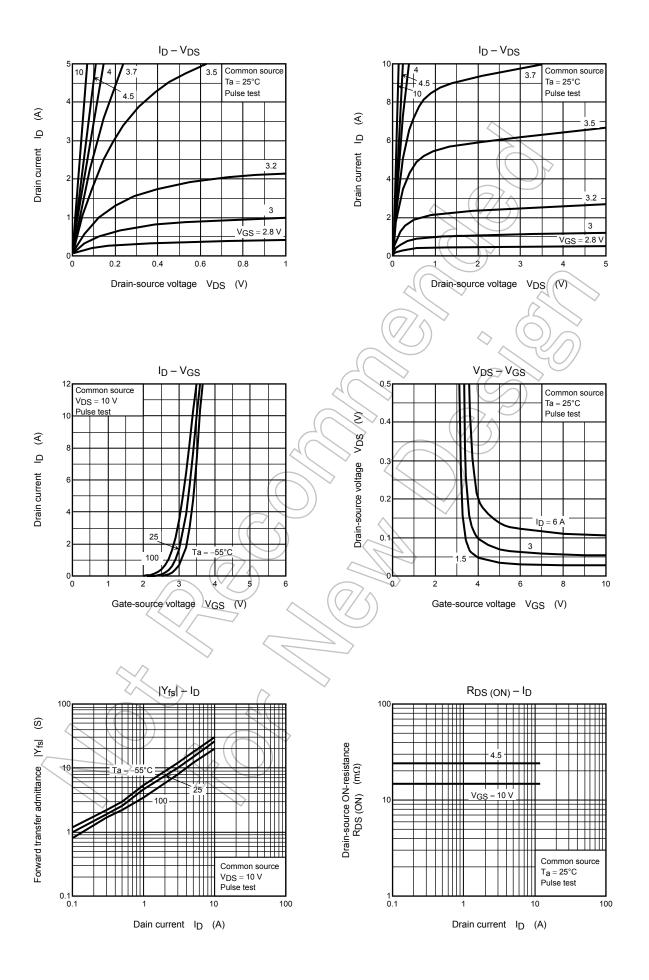


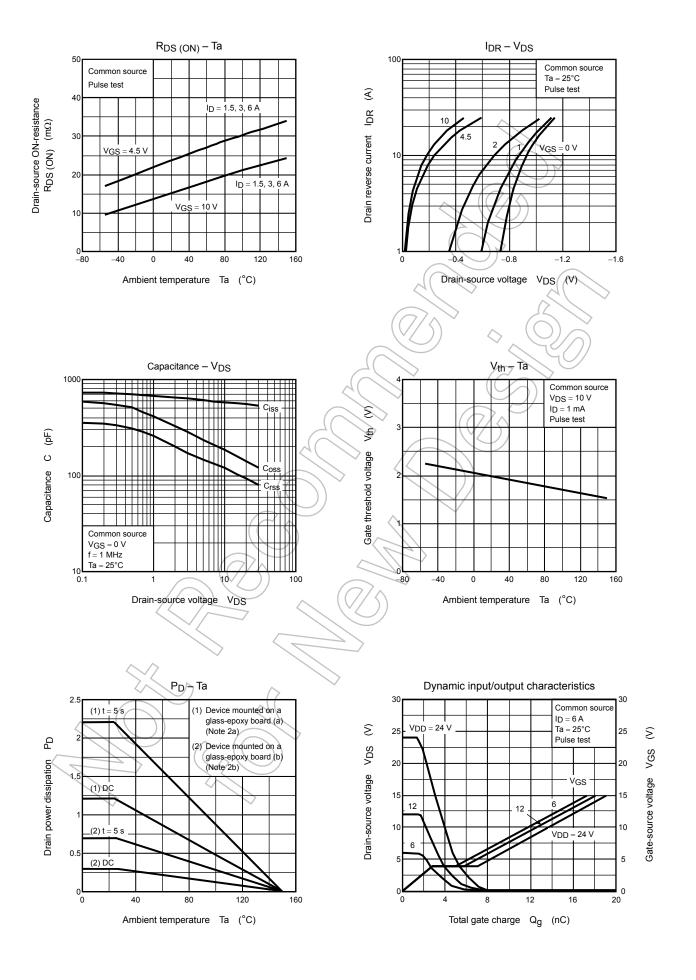
### **Electrical Characteristics (Ta = 25°C)**

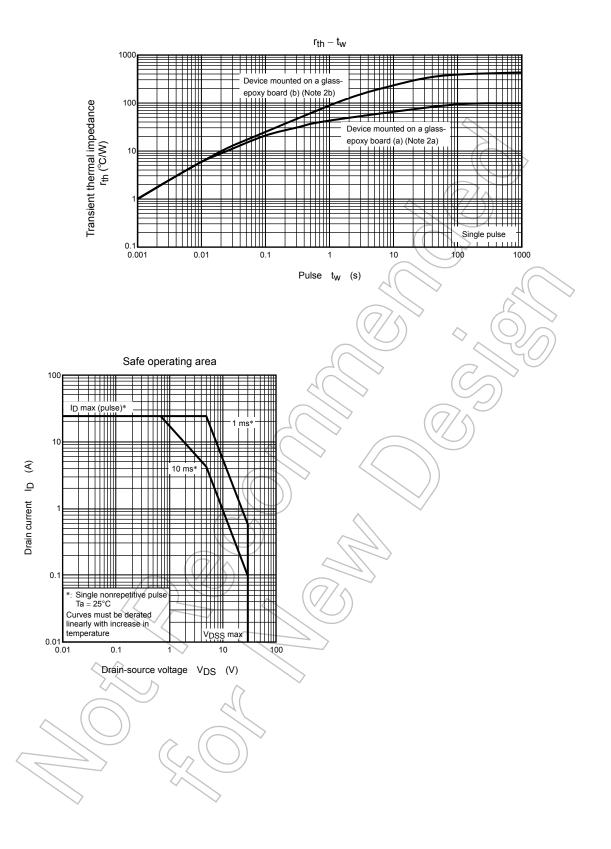
Characteristics		Symbol	Test Condition	Min	Тур.	Max	Unit	
Gate leakage cui	rrent	I <sub>GSS</sub>	$V_{GS} = \pm 20 \text{ V}, V_{DS} = 0 \text{ V}$	±100		±100	nA	
Drain cut-off curr	ent	I <sub>DSS</sub>	V <sub>DS</sub> = 30 V, V <sub>GS</sub> = 0 V	_	_	10	μА	
Drain-source breakdown voltage		V <sub>(BR) DSS</sub>	(BR) DSS $I_D = 10 \text{ mA}, V_{GS} = 0 \text{ V}$		_	_	V	
		V (BR) DSX	$I_D = 10 \text{ mA}, V_{GS} = -20 \text{ V}$	10	_	_	V	
Gate threshold voltage		V <sub>th</sub>	V <sub>DS</sub> = 10 V, I <sub>D</sub> = 1mA	1.3	) /_	2.5	V	
Drain-source ON-resistance		R <sub>DS</sub> (ON)	V <sub>GS</sub> = 4.5 V, I <sub>D</sub> = 3 A	) <u> </u>	24	32	mΩ	
		R <sub>DS</sub> (ON)	V <sub>GS</sub> =10 V, I <sub>D</sub> = 3 A	$\mathcal{P}$	16	20		
Forward transfer admittance		Y <sub>fs</sub>	V <sub>DS</sub> = 10 V, I <sub>D</sub> = 3 A	5	10	_	S	
Input capacitance		C <sub>iss</sub>		_	640	_		
Reverse transfer capacitance		C <sub>rss</sub>	$V_{DS} = 10 \text{ V}, V_{GS} = 0 \text{ V}, f = 1 \text{ MHz}$	_	125	_	pF	
Output capacitance		Coss		/	185	$\rightarrow$		
Switching time	Rise time	t <sub>r</sub>	V <sub>GS</sub> 10   I <sub>D</sub> = 3 A O V <sub>OUT</sub>	-(	5.8	> _		
	Turn-on time	t <sub>on</sub>	G S S S S S S S S S S S S S S S S S S S		12	_		
	Fall time	t <sub>f</sub>	4 m m 9 g	(2)	8	_	ns	
	Turn-off time	t <sub>off</sub>	$V_{DD} \approx 15 \text{ V}$ Duty \le 1%, t <sub>w</sub> = 10 \text{ \mus}	) —	24.5	_		
Total gate charge (gate-source plus gate-drain)		Qg		_	14	_		
Gate-source charge 1		Q <sub>gs 1</sub>	$V_{DD} \approx 24 \text{ V}, V_{GS} = 10 \text{ V}, I_D = 6 \text{ A}$	_	2.7	_	nC	
Gate-drain ("miller") charge		Q <sub>gd</sub>	,	_	4.2	_		

## Source-Drain Ratings and Characteristics (Ta = 25°C)

Charact	teristics	Symbol	Test Condition	Min	Тур.	Max	Unit
Drain reverse current	Pulse (Note 1)	IDRP		ı	_	24	А
Forward voltage	(diode)	V <sub>DSF</sub>	$I_{DR} = 6 \text{ A}, V_{GS} = 0 \text{ V}$	_	_	- 1.2	V







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